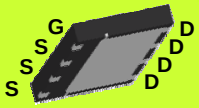
N-Channel

CICLON NexFET™ Power MOSFETs

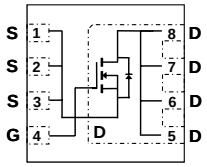
CSD16406Q3

Features

- Ultra Low Qg & Qgd
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free



QFN 3.3mm x 3.3mm Plastic Package



Top View

Product Summary

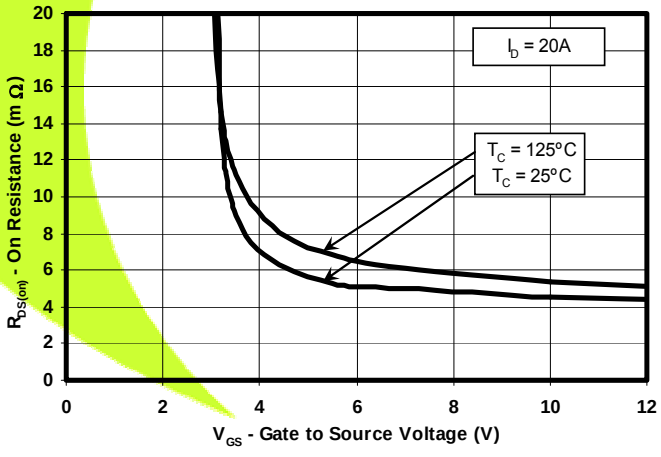
V_{DS}	25		V
Q_g	5.8		nC
Q_{gd}	1.5		nC
$R_{DS(on)}$	V_{GS}=4.5V	5.9	mΩ
	V_{GS}=10V	4.2	mΩ
V_{th}	1.7		V

Maximum Values (T_A=25°C unless otherwise stated)

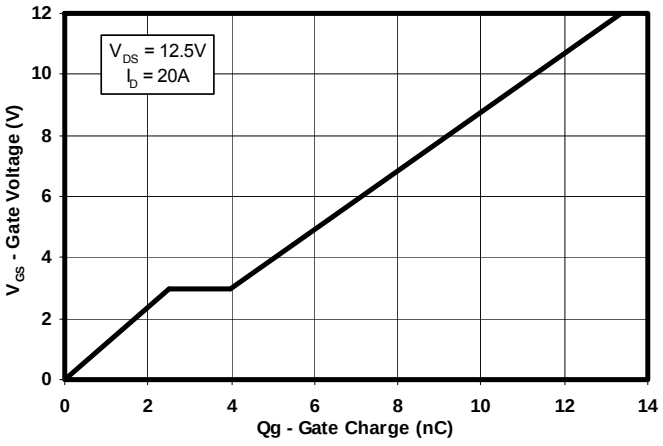
Symbol	Parameter	Value	Units
V_{DS}	Drain to Source Voltage	25	V
V_{GS}	Gate to Source Voltage	+16 / -12	V
I_D	Continuous Drain Current, T_C = 25°C	60	A
	Continuous Drain Current[1]	19	A
I_{DM}	Pulsed Drain Current, T_A = 25°C[2]	114	A
P_D	Power Dissipation[1]	2.7	W
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E_{AS}	Avalanche Energy, single pulse I_D =45A, L = 0.1mH, R_G = 25Ω	101	mJ

1. Rθja = 46°C/W on 1in² Cu (2 oz.) on 0.060" thick FR4 PCB.
2. Pulse width ≤300 µs, duty cycle ≤ 2%

$R_{DS(ON)}$ vs. V_{GS}



Gate Charge



Ordering Information

Type	Package	Package Media	Qty	Ship
CSD16406Q3	QFN 3.3 X 3.3 Plastic Package	13 inch reel	2500	Tape and Reel

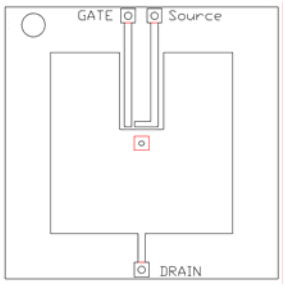
Electrical Characteristics (T_A = 25°C unless otherwise stated)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Static Characteristics						
BV_{DSS}	Drain to Source Voltage	V_{GS} = 0V, I_D = 250µA	25	—	—	V
I_{DSS}	Drain to Source Leakage Current	V_{GS} = 0V, V_{DS} = 20V	—	—	1	µA
I_{GSS}	Gate to Source Leakage Current	V_{DS} = 0V, V_{GS} = +16/-12V	—	—	100	nA
$V_{GS(th)}$	Gate to Source Threshold Voltage	V_{DS} = V_{GS}, I_D = 250µA	1.4	1.7	2.2	V
$R_{DS(on)}$	Drain to Source On Resistance	V_{GS} = 4.5V, I_D = 20A	—	5.9	7.4	mΩ
		V_{GS} = 10V, I_D = 20A	—	4.2	5.3	mΩ
g_{fs}	Transconductance	V_{DS} = 15V, I_D = 20A	—	53	—	S
Dynamic Characteristics						
C_{ISS}	Input Capacitance	V_{GS} = 0V, V_{DS} = 12.5V f = 1MHz	—	840	1100	pF
C_{OSS}	Output Capacitance		—	680	950	pF
C_{RSS}	Reverse Transfer Capacitance		—	57	80	pF
R_g	Series Gate Resistance		—	1.4	—	Ω
Q_g	Gate Charge Total (4.5V)	V_{DS} = 12.5V, I_D =20A	—	5.8	8.1	nC
Q_{gd}	Gate Charge Gate to Drain		—	1.5	—	nC
Q_{gs}	Gate Charge Gate to Source		—	2.5	—	nC
$Q_{g(th)}$	Gate Charge at Vth		—	1.5	—	nC
Q_{OSS}	Output Charge	V_{DS} = 13.6V, V_{GS} = 0V	—	13.9	—	nC
$t_{d(on)}$	Turn On Delay Time	V_{DS} = 12.5V V_{GS} = 4.5V I_D = 20A R_G = 7.5 Ω	—	10.4	—	ns
t_r	Rise Time		—	20	—	ns
$t_{d(off)}$	Turn Off Delay Time		—	9.4	—	ns
t_f	Fall Time		—	29	—	ns
Diode Characteristics						
V_{SD}	Diode Forward Voltage	I_S = 20A, V_{GS} = 0V	—	0.85	1.0	V
Q_{rr}	Reverse Recovery Charge	V_{dd}=13.6V, I_F = 20A, di/dt = 300A/µs	—	18	—	nC
t_{rr}	Reverse Recovery Time	V_{dd}=13.6V, I_F = 20A, di/dt = 300A/µs	—	22	—	ns

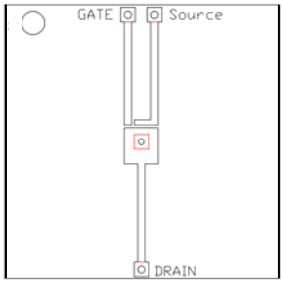
Thermal Characteristics (T_A = 25°C unless otherwise stated)

Symbol	Parameter	Min	Typ	Max	Units
Thermal Characteristics					
$R_{\theta JC}$	Thermal Resistance Junction to Case[3]	—	—	2.7	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient[3,4]	—	—	58	°C/W

3. $R_{\theta jc}$ is determined with the device mounted on a 1in square 2 oz. Cu pad on a 1.5x1.5 in .060in thick FR4 board. $R_{\theta jc}$ is guaranteed by design while $R_{\theta ca}$ is determined by the user's board design.
4. Device mounted on FR4 Material with 1in^2 of 2 oz. Cu.



Max Rθja =58 °C/W when mounted on 1in^2 of 2 oz. Cu.



Max Rθja =162 °C/W when mounted on min pad area of 2 oz. Cu.

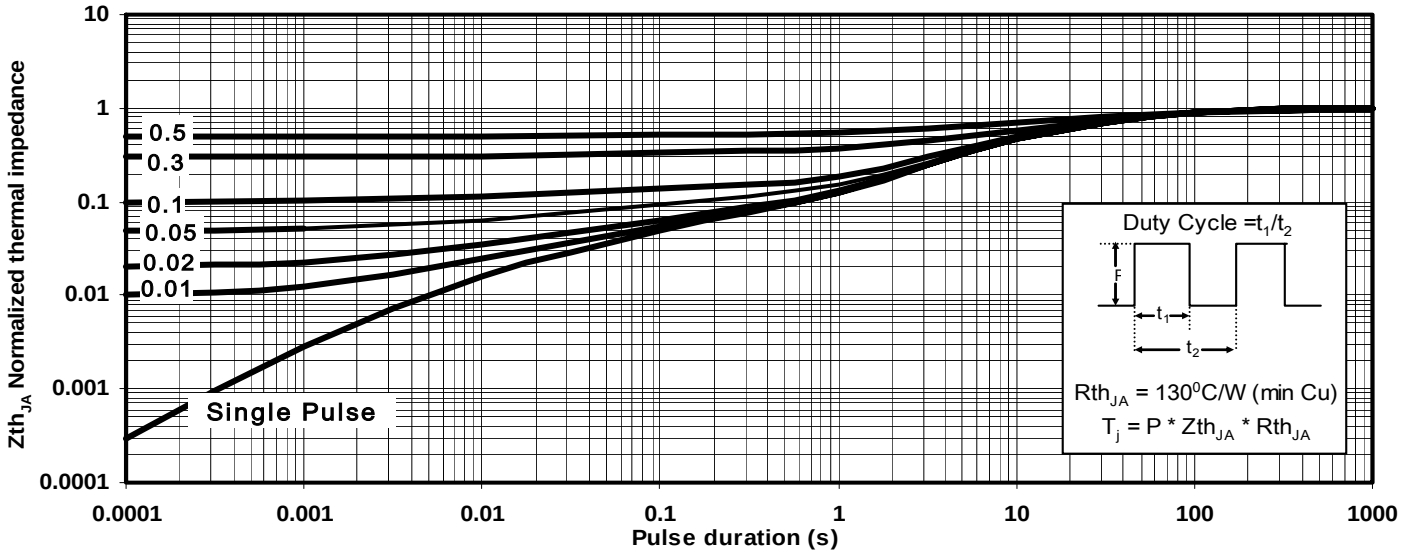


Figure 1: Transient Thermal Impedance

Typical MOSFET Characteristics (T_A = 25°C unless otherwise stated)

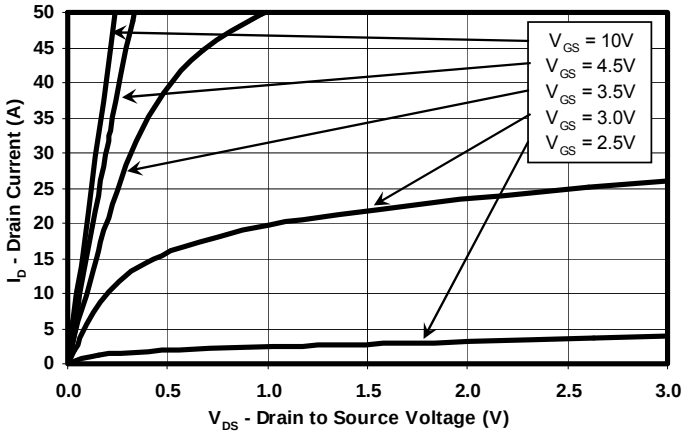


Figure 2: Saturation Characteristics

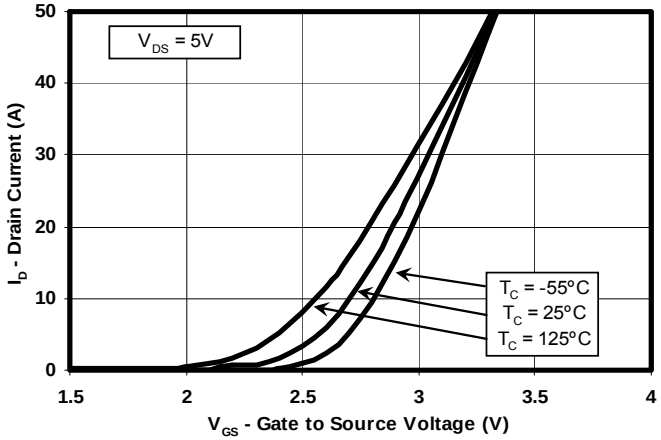


Figure 3: Transfer Characteristics

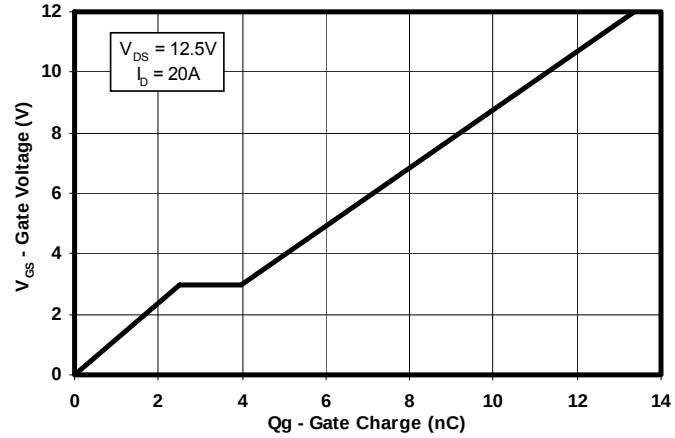


Figure 4: Gate Charge

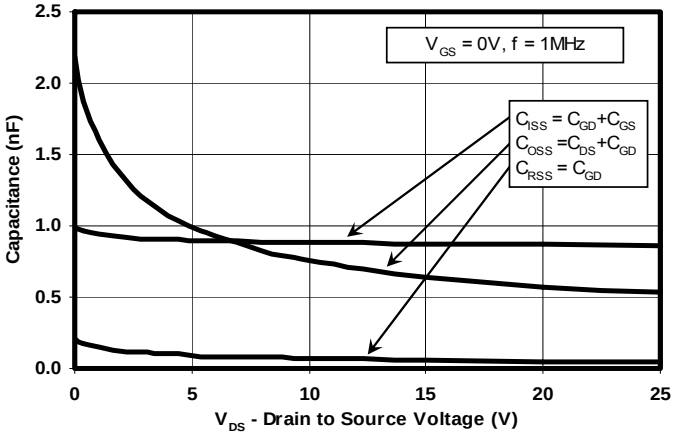


Figure 5: Capacitance

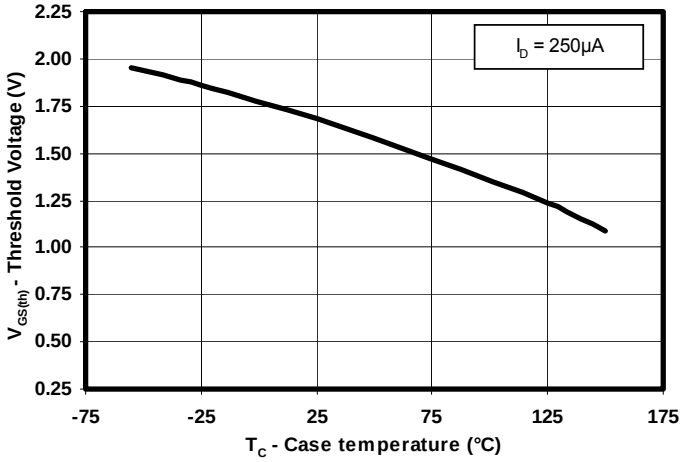


Figure 6: Threshold Voltage vs. Temperature

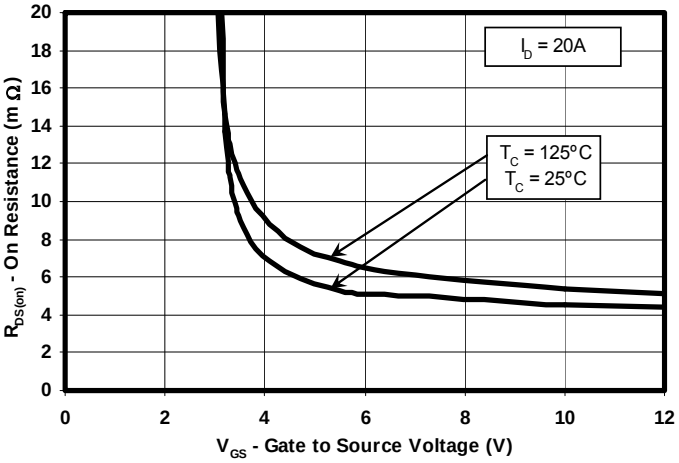


Figure 7: On Resistance vs. Gate Voltage

Typical MOSFET Characteristics (T_A = 25°C unless otherwise stated)

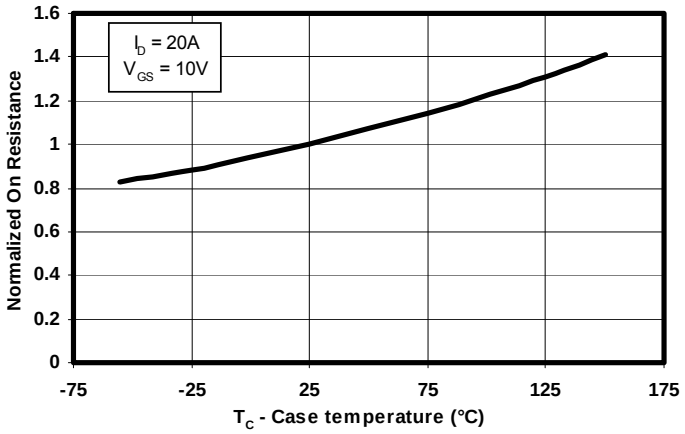


Figure 8: On Resistance vs. Temperature

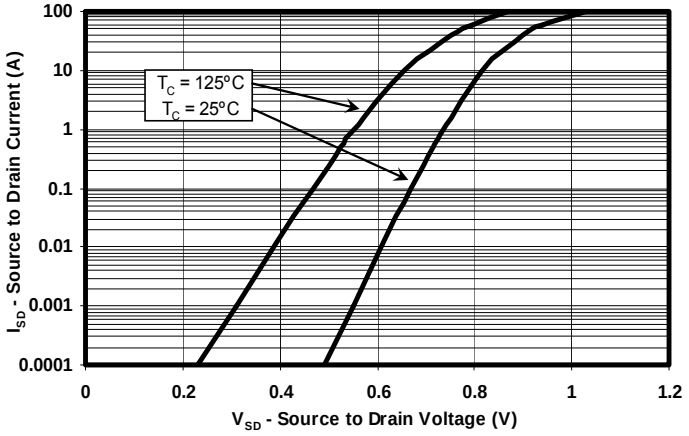


Figure 9: Typical Diode Forward Voltage

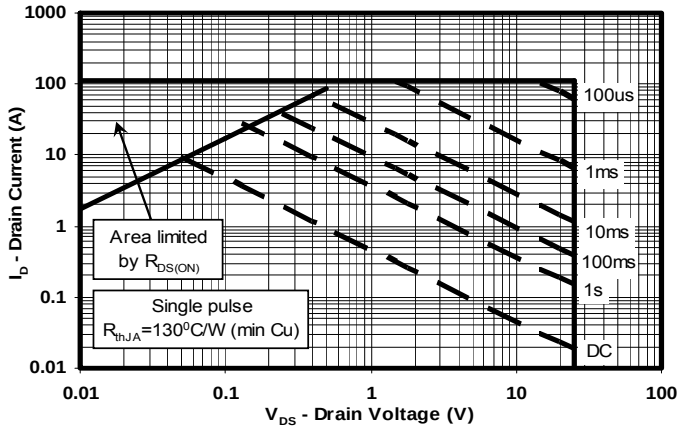


Figure 10: Maximum Safe Operating Area

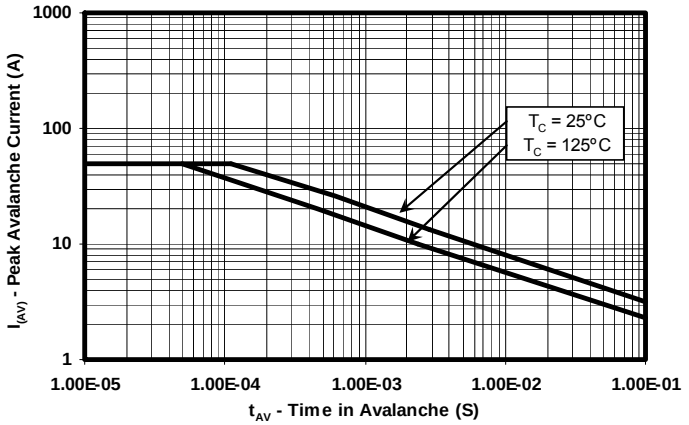


Figure 11: Single Pulse Unclamped Inductive Switching

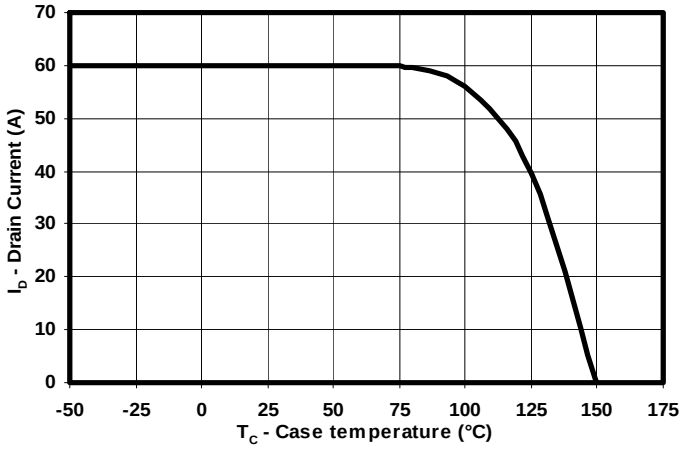
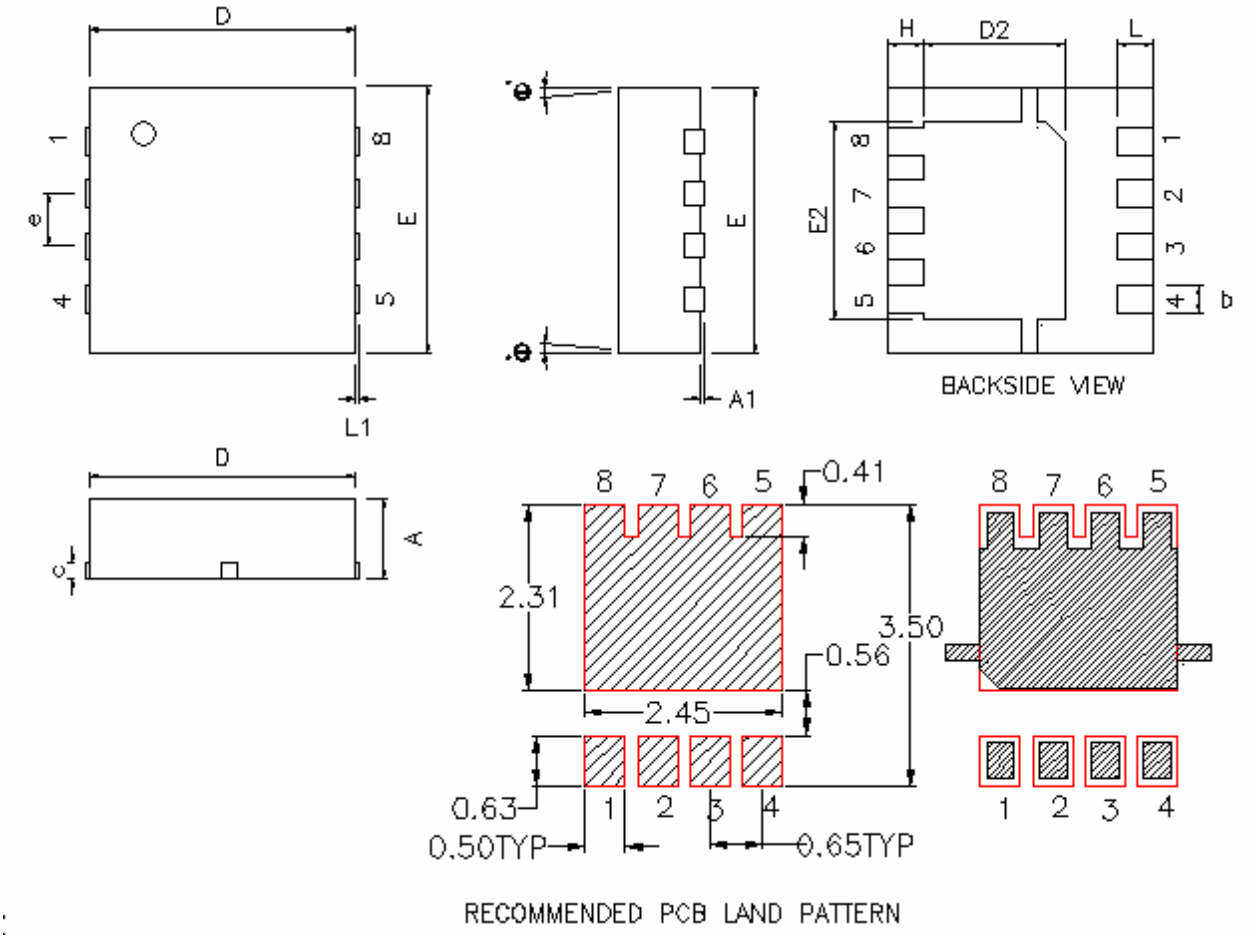


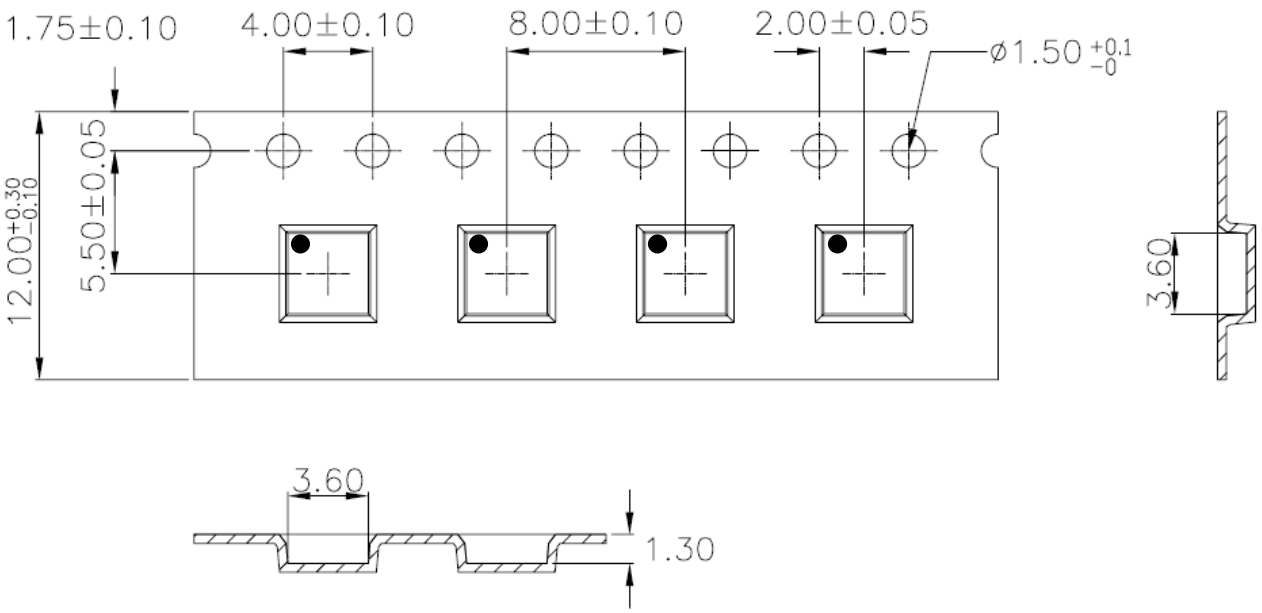
Figure 12: Maximum Drain Current vs. Temperature

CSD16406Q3 Package Dimensions



DIM	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
A	0.950	1.000	1.100	0.037	0.039	0.043
A1	0.000	0.000	0.050	0.000	0.000	0.002
b	0.280	0.340	0.400	0.011	0.013	0.016
c	0.150	0.200	0.250	0.006	0.008	0.010
D	3.200	3.300	3.400	0.126	0.130	0.134
D1	-	-	-	-	-	-
D2	1.650	1.750	1.800	0.065	0.069	0.071
E	3.200	3.300	3.400	0.126	0.130	0.134
E1	-	-	-	-	-	-
E2	2.350	2.450	2.550	0.093	0.096	0.100
e	0.650 TYP			0.026		
H	0.35	0.450	0.550	0.014	0.018	0.022
L	0.35	0.450	0.550	0.014	0.018	0.022
L1	-	-	-	-	-	-
θ	-	-	-	-	-	-

Q3 Tape and Reel Information



Note:

1. 10 SPROCKET HOLE PITCH CUMULATIVE TOLERANCE +/-0.2
2. CAMBER NOT TO EXCEED 1mm IN 100mm, NONCUMULATIVE OVER 250mm
3. MATERIAL:BLACK STATIC DISSIPATIVE POLYSTYRENE
4. ALL DIMENSIONS ARE IN mm (UNLESS OTHERWISE SPECIFIED)
5. THICKNESS: 0.30 +/-0.05mm

Package Marking Information

Location:

1st Line

CSD = Fixed Characters

NNNNN = Product Code

2nd Line (Date Code)

YY = Last 2 digits of the Year

WW = 2-digit Work Week

C = Country of Origin

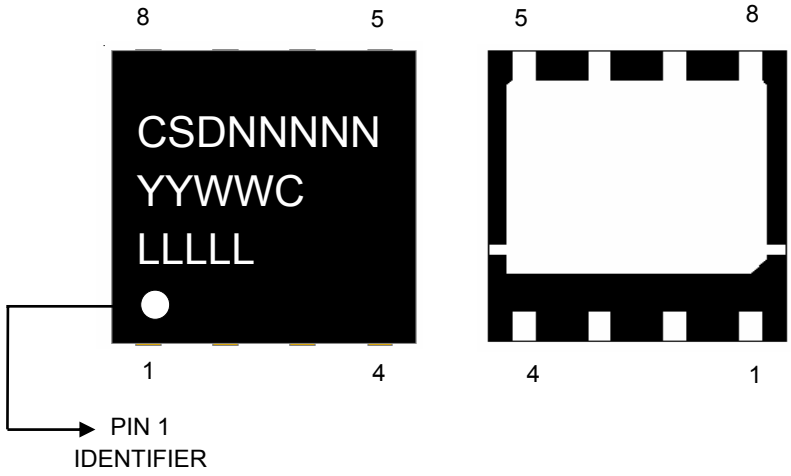
> Philippines = P

> Taiwan = T

> China = C

3rd Line

LLLLL= Last 5 digits of the Wafer Lot #



N-Channel
CICLON NexFET™ Power MOSFETs
CSD16406Q3

Disclaimer
CICLON Semiconductor Device Corp. ("**CICLON**") reserves the right to make corrections, modifications, enhancements, improvements and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to **CICLON**'s terms and conditions of sale supplied at the time of order acknowledgement.

Additional Information
For further information on technology, delivery terms and conditions, or pricing please contact your nearest **CICLON** Semiconductor representative.

CICLON Semiconductor Device Corp.
116 Research Drive, Bethlehem, PA 18015
T 610-849-5100 **F** 610-849-5101

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)
CSD16406Q3	ACTIVE	SON	DQG	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		**Applications**	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DLP® Products	www.dlp.com	Broadband	www.ti.com/broadband
DSP	dsp.ti.com	Digital Control	www.ti.com/digitalcontrol
Clocks and Timers	www.ti.com/clocks	Medical	www.ti.com/medical
Interface	interface.ti.com	Military	www.ti.com/military
Logic	logic.ti.com	Optical Networking	www.ti.com/opticalnetwork
Power Mgmt	power.ti.com	Security	www.ti.com/security
Microcontrollers	microcontroller.ti.com	Telephony	www.ti.com/telephony
RFID	www.ti-rfid.com	Video & Imaging	www.ti.com/video
RF/IF and ZigBee® Solutions	www.ti.com/lprf	Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265